

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Number 7,023,059  
Issued 4/4/2006  
Name of Patentee Darin A. Chan  
Title of Invention TRENCHES TO REDUCE LATERAL SILICIDE GROWTH IN  
INTEGRATED CIRCUIT TECHNOLOGY

ATTN: Certificate of Correction Branch  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

REQUEST FOR CERTIFICATE OF CORRECTION OF PATENT

Please issue a Certificate of Correction for the following mistakes in the above-referenced patent

☒ **FOR PTO MISTAKE (37 C.F.R. § 1.322(a))**

The exact page and line number where the errors are shown correctly in the application file are:

1. In the specification, page 7, line 14
2. In the specification, page 7, line 17

The exact column and line number where the error occurs in the Patent are:

1. Column 5, line 28, delete "suicides" and insert therefor --silicides--
2. Column 5, line 31, delete "suicides" and insert therefor --silicides--

☒ Attached hereto, in duplicate, is Form PTO-1050, with at least one copy being suitable for printing.

☒ Please send the Certificate to:

Name Mikio Ishimaru  
Address The Law Offices of Mikio Ishimaru  
333 W. El Camino Real, Suite #330  
Sunnyvale, CA 94087

☐ Charge Deposit Account 50-0374 the sum of \$0.00, as required by 37 CFR 1.20(a), and the fee for      additional copies of the Certificate of Correction. A duplicate of this request is attached.

CERTIFICATE OF MAILING/TRANSMISSION (37 C.F.R.1.8a)

I hereby certify that this correspondence is on the date shown below being:

☒ Submitted to the United States Patent and Trademark Office via the Electronic Filing System.

Date: 4/14/06

Signature Meghan Calhoun  
Meghan Calhoun

☒ Please charge any shortage in fees due in connection with the filing of this paper to Deposit Account No. 50-0374 and credit any excess fees to such deposit account.

Mikio Ishimaru

Mikio Ishimaru

Reg. No.: 27,449

Date: April 14, 2006